Time: 2½

Total Marks: 60

N.I	B. : (l) All	questions are compulsory .	Y ES			
	(2	2) Fig	gures to the right indicate full marks.				
	(.	3) Dra	aw neat diagrams wherever necessary .				
(4) Symbols have usual meanings unless otherwise stated.							
	(:	5) Us	e of non-programmable calculator is allowed.				
1.	(a)	Attempt any one:					
		(i)	Sketch the energy band diagram, charge distribution, electric filed	8			
			distribution and potential distribution of an ideal MOS diode.				
		(ii)	Draw a labeled diagram of MOSFET with an appropriate explanation of its	8			
			current-voltage (I-V) characteristics under ideal conditions and determine				
			the channel conductance and transconductance.				
	(b)	Atte	mpt any one:				
		(i)	Write note on simulation.	4			
		(ii)	Write note on a volatile memory devices and its use.	4			
2.	(a)	Attempt any one:					
		(i)	Draw a labeled diagram of Tunnel diode and discuss in detail its current-	8			
		20	voltage (I-V) characteristics.				
		(ii)	Explain in detail the construction and working of BARITT diode.	8			
	(b) Attempt any one:		mpt any one:				
	V 2 2 3	(i)	Write note on transferred electron devices.	4			
		(ii)	Draw a schematic diagram and symbol of thyristor.	4			
3.	(a)	Attempt any one:					
96		(i)	Define photodetectors. Draw a schematic diagram of photoconductor and	8			
15.7			explain its operation under illumination and illustrate mathematical				
			relation for photocurrent gain.				
		(ii)	What are the fiber materials? Explain fiber optical waveguide and	8			
		222	transportation of light signal? Explain any one technique to manufacture				
	300		the optical fiber.				
120		7.50					

72929 Page 1 of 2

	(b)	Attempt any one:					
		(i)	Write note on semiconductor solar cell.	¥ 2° 4			
		(ii)	Write note on amorphous silicon solar cells.	4			
4.	(a)	Atte	mpt any one:				
		(i)	Explain briefly nanomaterials and describe any one method to synthesize	8			
			semiconductor nanomaterials and state their properties which are different				
			than the bulk materials.				
		(ii)	Explain briefly the theory of colloids. How are the metal nanoparticles	8			
			synthesized by the colloidal method?				
	(b)	Attempt any one:					
		(i)	Bulk nanostructured materials	4			
		(ii)	Write note on carbon nanostructures	4			
5.		Attempt any four:					
	(a)	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~		3			
	(b)	Y 2 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8		3			
	(c)	Explain in brief bipolar power transistor.		3			
	(d)	Write short note on Gunn diode.		3			
	(e)	Write short note on applications of semiconductor LASER.		3			
	(f)	Write note on liquid crystal display.		3			
	(g)	~~````````````````````````````````````					
	(h)	544574400058660844854		3			
	V S	20 20 2	88888600000000000000000000000000000000				

72929 Page 2 of 2